

CMDD6001

SUPERmini™
SURFACE MOUNT
LOW LEAKAGE
SWITCHING DIODE

SUPERmini™



SOD-323 CASE

Central™
Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMDD6001 type is a silicon switching diode manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, designed for switching applications requiring a extremely low leakage diode.

THE MARKING CODE IS C61.

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$)

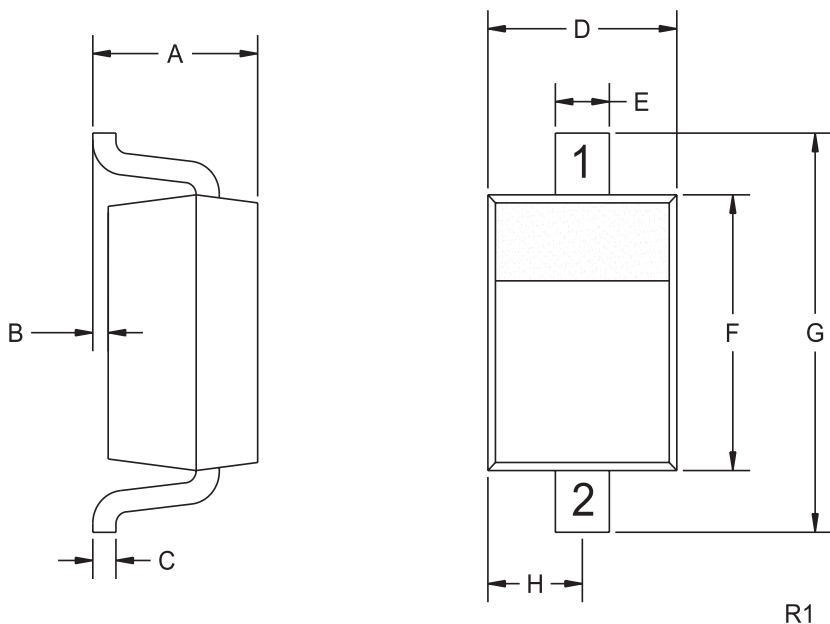
	SYMBOL		UNITS
Continuous Reverse Voltage	V_R	75	V
Peak Repetitive Reverse Voltage	V_{RRM}	100	V
Continuous Forward Current	I_F	250	mA
Peak Repetitive Forward Current	I_{FRM}	250	mA
Forward Surge Current, $t_p=1.0\text{ }\mu\text{sec.}$	I_{FSM}	4000	mA
Forward Surge Current, $t_p=1.0\text{ sec.}$	I_{FSM}	1000	mA
Power Dissipation	P_D	250	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance	Θ_{JA}	500	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	$V_R=75\text{V}$		500	pA
V_{BR}	$I_R=100\mu\text{A}$	100		V
V_F	$I_F=1.0\text{mA}$		0.85	V
V_F	$I_F=10\text{mA}$		0.95	V
V_F	$I_F=100\text{mA}$		1.1	V
C_T	$V_R=0$, $f=1.0\text{MHz}$		2.0	pF
t_{rr}	$I_R=I_F=10\text{mA}$, $R_L=100\Omega$, Rec. to 1.0mA		3.0	μs

R1 (20-July 2001)

SOD-323 - MECHANICAL OUTLINE



LEAD CODE:

- 1) Cathode
- 2) Anode

MARKING CODE: C61

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.039	0.043	1.00	1.10
B	0.000	0.004	0.00	0.10
C	0.005	0.008	0.14	0.22
D	0.045	0.053	1.15	1.35
E	0.011	0.015	0.28	0.38
F	0.063	0.071	1.60	1.80
G	0.094	0.102	2.40	2.60
H	0.023	0.027	0.58	0.68

SOD-323 (REV: R1)

R1 (20-July 2001)